

BTS4880R

Eight Channels: 8 x 200 mΩ

Smart Power High-Side Switch

Data sheet

Rev. 1.2, 2014-12-15

Automotive Power

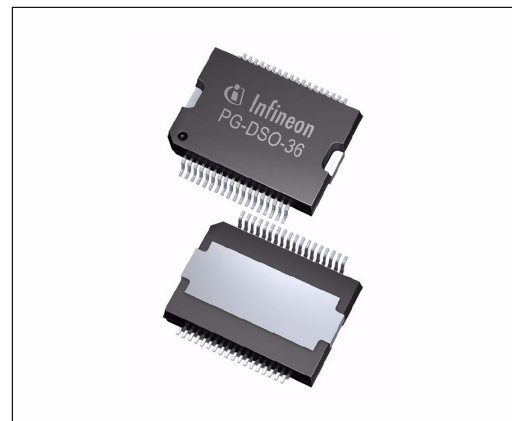


Features

- Output current 0,625 A per channel
- Short circuit protection
- Maximum current internally limited
- Overload protection
- Input protection
- Overvoltage protection (including load dump)
- Undervoltage shutdown with auto-restart and hysteresis
- Switching inductive loads
- Thermal shutdown with restart
- Thermal independence of separate channels
- ESD - Protection
- Loss of GND and loss of V_{bb} protection
- Very low standby current
- Reverse battery protection
- Programmable input for CMOS or $V_{bb}/2$
- Common diagnostic output (current output) for overtemperature

Product Summary

Overvoltage protection	$V_{bb(AZ)}$	47	V
Operating voltage	$V_{bb(on)}$	11...45	V
On-state resistance	R_{ON}	200	m Ω



PG-DSO-36

- AEC Qualified
- Green Product (RoHS compliant)

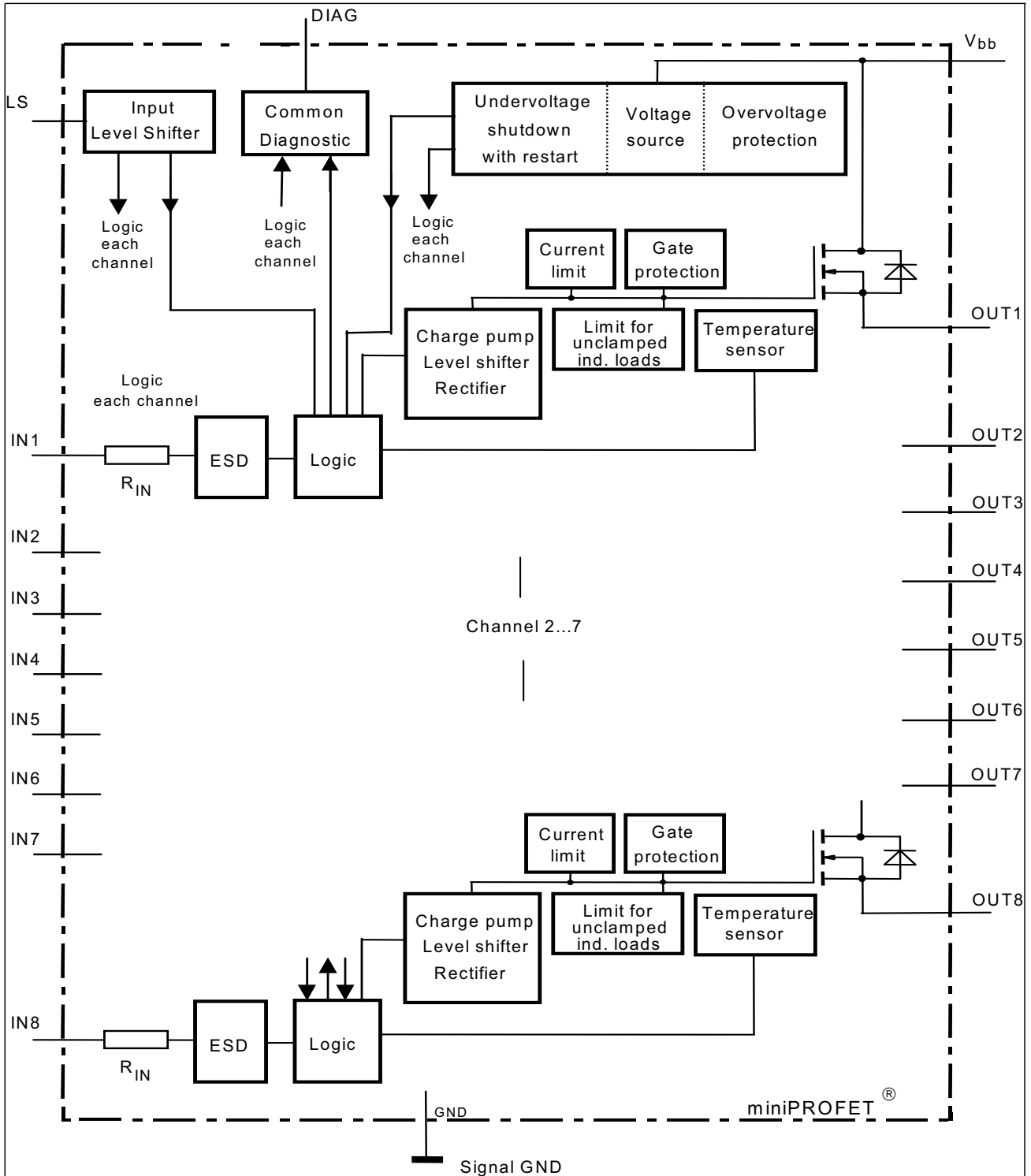
Application

- Output driver for industrial applications (PLC)
- All types of resistive, inductive and capacitive loads
- μ C or optocoupler compatible power switch for 24 V DC applications
- Replaces electromechanical relays and discrete circuits

General Description

N channel vertical power FET with charge pump, ground referenced CMOS or $V_{bb}/2$ compatible input and common diagnostic feedback, monolithically integrated in Smart SIPMOS® technology. Providing embedded protective functions.

Block Diagram



Pin	Symbol	Function
1,2,4,5	NC	not connected
3	LS	Enable pin for switching the input-levels to $V_{bb}/2$
6	IN1	Input, activates channel 1 in case of logic high signal
7	IN2	Input, activates channel 2 in case of logic high signal
8	IN3	Input, activates channel 3 in case of logic high signal
9	IN4	Input, activates channel 4 in case of logic high signal
10	IN5	Input, activates channel 5 in case of logic high signal
11	IN6	Input, activates channel 6 in case of logic high signal
12	IN7	Input, activates channel 7 in case of logic high signal
13	IN8	Input, activates channel 8 in case of logic high signal
14-18	NC	not connected
19	GND	Logic ground
20	DIAG	Common diagnostic output for overtemperature
21	OUT8	High-side output of channel 8
22	OUT8	High-side output of channel 8
23	OUT7	High-side output of channel 7
24	OUT7	High-side output of channel 7
25	OUT6	High-side output of channel 6
26	OUT6	High-side output of channel 6
27	OUT5	High-side output of channel 5
28	OUT5	High-side output of channel 5
29	OUT4	High-side output of channel 4
30	OUT4	High-side output of channel 4
31	OUT3	High-side output of channel 3
32	OUT3	High-side output of channel 3
33	OUT2	High-side output of channel 2
34	OUT2	High-side output of channel 2
35	OUT1	High-side output of channel 1
36	OUT1	High-side output of channel 1
TAB	V _{bb}	Positive power supply voltage

Maximum Ratings

Parameter	Symbol	Value	Unit
at $T_j = -40...135\text{ }^\circ\text{C}$, unless otherwise specified			
Supply voltage	V_{bb}	-1 ¹⁾ ...45	V
Continuous input voltage ²⁾	V_{IN}	-10... V_{bb}	
Continuous voltage at LS-pin	V_{LS}	-1... V_{bb}	
Load current (Short - circuit current, see page 6)	I_L	self limited	A
Current through input pin (DC), each channel	I_{IN}	± 5	mA
Reverse current through GND-pin ¹⁾	$-I_{GND}$	1.6	A
Operating temperature	T_j	internal limited	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 ... +150	
Power dissipation ³⁾	P_{tot}	3.3	W
Inductive load switch-off energy dissipation ⁴⁾ single pulse, $T_j = 125\text{ }^\circ\text{C}$, $I_L = 0.625\text{ A}$ one channel active all channels simultaneously active (each channel)	E_{AS}	10 1	J
Load dump protection ⁴⁾ $V_{LoadDump}^{5)} = V_A + V_S$ $V_{IN} = \text{low or high}$ $t_d = 400\text{ ms}$, $R_I = 2\ \Omega$, $R_L = 27\ \Omega$, $V_A = 13.5\text{ V}$ $t_d = 350\text{ ms}$, $R_I = 2\ \Omega$, $R_L = 47\ \Omega$, $V_A = 27\text{ V}$	$V_{Loaddump}$	90 117	V
Electrostatic discharge voltage (Human Body Model) according to ANSI EOS/ESD - S5.1 - 1993 ESD STM5.1 - 1998 Input pin, LS pin, Common diagnostic pin all other pins	V_{ESD}	± 1 ± 5	kV
Continuous reverse drain current ¹⁾⁴⁾ , each channel	I_S	4	A

¹⁾ defined by P_{tot}

²⁾ At $V_{IN} > V_{bb}$, the input current is not allowed to exceed $\pm 5\text{ mA}$.

³⁾ Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6 cm² (one layer, 70 μm thick) copper area for drain connection. PCB is vertical without blown air.

⁴⁾ not subject to production test, specified by design

⁵⁾ $V_{Loaddump}$ is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839 .

Supply voltages higher than $V_{bb(AZ)}$ require an external current limit for the GND pin, e.g. with a 150 Ω resistor in GND connection. A resistor for the protection of the input is integrated.

Electrical Characteristics

Parameter at $T_j = -25...125^\circ\text{C}$, $V_{bb} = 15...30\text{V}$, unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	

Thermal Characteristics

Thermal resistance junction - case	R_{thJC}	-	-	1.5	K/W
Thermal resistance @ min. footprint	$R_{th(JA)}$	-	-	50	
Thermal resistance @ 6 cm ² cooling area ¹⁾	$R_{th(JA)}$	-	-	38	

Load Switching Capabilities and Characteristics

On-state resistance $T_j = 25^\circ\text{C}$, $I_L = 0.5\text{ A}$ $T_j = 125^\circ\text{C}$	R_{ON}	-	150 270	200 320	m Ω
Turn-on time to 90% V_{OUT} $R_L = 47\ \Omega$, $V_{IN} = 0$ to 10 V	t_{on}	-	50	100	
Turn-off time to 10% V_{OUT} $R_L = 47\ \Omega$, $V_{IN} = 10$ to 0 V	t_{off}	-	75	150	
Slew rate on 10 to 30% V_{OUT} , $R_L = 47\ \Omega$, $V_{bb} = 15\text{ V}$	dV/dt_{on}	-	1	2	V/ μs
Slew rate off 70 to 40% V_{OUT} , $R_L = 47\ \Omega$, $V_{bb} = 15\text{ V}$	$-dV/dt_{off}$	-	1	2	

¹ Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6 cm² (one layer, 70 μm thick) copper area for drain connection. PCB is vertical without blown air.

Electrical Characteristics

Parameter at $T_j = -25...125^\circ\text{C}$, $V_{bb}=15...30\text{V}$, unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	
Operating Parameters					
Operating voltage	$V_{bb(\text{on})}$	11	-	45	V
Undervoltage shutdown	$V_{bb(\text{under})}$	7	-	10.5	
Undervoltage restart	$V_{bb(\text{u rst})}$	-	-	11	
Undervoltage hysteresis $\Delta V_{bb(\text{under})} = V_{bb(\text{u rst})} - V_{bb(\text{under})}$	$\Delta V_{bb(\text{under})}$	-	0.5	-	
Standby current	$I_{bb(\text{off})}$	-	50	150	μA
Operating current ¹⁾	I_{GND}	-	5	12	mA
Leakage output current (included in $I_{bb(\text{off})}$) $V_{\text{IN}} = \text{low}$, each channel	$I_{\text{L}(\text{off})}$	-	5	10	μA

Protection Functions²⁾

Initial peak short circuit current limit $T_j = -25^\circ\text{C}$, $V_{bb} = 30\text{V}$, $t_m = 700\ \mu\text{s}$ $T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$	$I_{\text{L}(\text{SCP})}$	- - 0.7	- 1.4 -	1.9 - -	A
Repetitive short circuit current limit $T_j = T_{jt}$ (see timing diagrams)	$I_{\text{L}(\text{SCR})}$	-	1.1	-	
Output clamp (inductive load switch off) at $V_{\text{OUT}} = V_{bb} - V_{\text{ON}(\text{CL})}$,	$V_{\text{ON}(\text{CL})}$	47	53	60	V
Overvoltage protection ³⁾	$V_{bb(\text{AZ})}$	47	-	-	
Thermal overload trip temperature ⁴⁾	T_{jt}	135	-	-	$^\circ\text{C}$
Thermal hysteresis	ΔT_{jt}	-	10	-	K

¹⁾contains all input currents

²⁾Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

³⁾ see also $V_{\text{ON}(\text{CL})}$ in circuit diagram on page 10

⁴⁾ higher operating temperature at normal function for each channel available

Electrical Characteristics

Parameter at $T_j = -25...125^\circ\text{C}$, $V_{bb}=15...30\text{V}$, unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	
Input					
Continuous input voltage ¹⁾	V_{IN}	-10	-	V_{bb}	V
Input turn-on threshold voltage CMOS ²⁾	$V_{IN(T+)}$	-	-	2.2	
Input turn-off threshold voltage CMOS ²⁾	$V_{IN(T-)}$	0.8	-	-	
Input turn-on threshold voltage $V_{bb}/2$ ²⁾	$V_{IN(T+)}$	-	-	$V_{bb}/2+1$	
Input turn-off threshold voltage $V_{bb}/2$ ²⁾	$V_{IN(T-)}$	$V_{bb}/2-1$	-	-	
Input threshold hysteresis	$\Delta V_{IN(T)}$	-	0.3	-	
Off state input current CMOS (each channel)	$I_{IN(off)}$	8	-	-	μA
On state input current CMOS (each channel)	$I_{IN(on)}$	-	-	70	
Off state input current $V_{bb}/2$ (each channel)	$I_{IN(off)}$	80	-	-	
On state input current $V_{bb}/2$ (each channel)	$I_{IN(on)}$	-	-	260	
Input delay time at switch on V_{bb}	$t_d(V_{bbon})$	150	340	-	μs
Input resistance (see page 10)	R_I	2	3	4	k Ω
Internal pull down resistor at LS-pin ³⁾	R_{LS}	300	800	-	

Diagnostic Characteristics

Common diagnostic output current ⁴⁾ (overtemperature of any channel) $T_j = 135^\circ\text{C}$	I_{diag}	2	3	4	mA
Common diagnostic output leakage current	$I_{diag(high)}$	-	-	2	μA

¹At $V_{IN} > V_{bb}$, the input current is not allowed to exceed ± 5 mA.

²see page 9

³LS-pin is connected to V_{bb}

⁴see page 10

Electrical Characteristics

Parameter at $T_j = -25...125^\circ\text{C}$, $V_{bb}=15...30\text{V}$, unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	
Reverse Battery					
Reverse battery voltage ¹⁾ $R_{GND} = 0 \Omega$ $R_{GND} = 150 \Omega$	$-V_{bb}$	-	-	1 45	V
Diode forward on voltage $I_F = 1.25 \text{ A}$, $V_{IN} = \text{low}$, each channel	$-V_{ON}$	-	-	1.2	

¹defined by P_{tot}

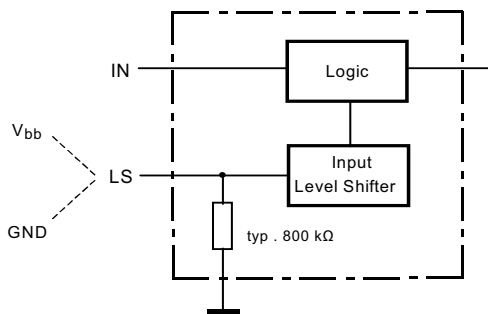
Truth table for common diagnostic pin (LED-driver):

	Input level	Output level	Diagnostic
Normal operation	L	L	L
	H	H	L
Short circuit to GND	L	L	L
	H	L	L
Undervoltage	L	L	L
	H	L	L
Overtemperature	L	L	L
	H	L	H ¹⁾

L = no diagnostic output current

H = diagnostic output current typ. 2 mA (see page 7)

Programmable input:



Functional description LS-Pin:

With using the LS-pin it is possible to change the input turn-on and -off threshold voltage between CMOS and half supply voltage level.

Therefore you have either to connect the LS-pin to device GND (state 1) or to supply voltage (state 2).

State 1: LS-Pin to GND

State 2: LS-Pin to supply voltage

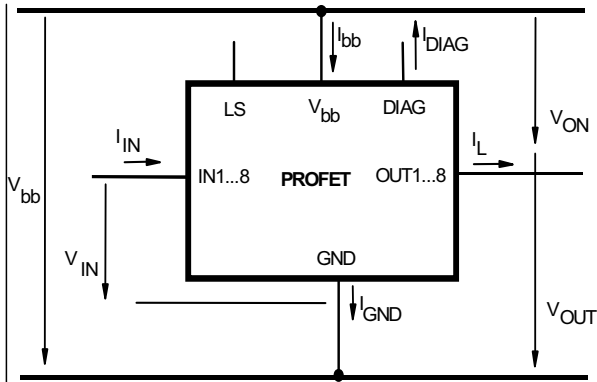
CMOS - Input level

$V_{bb}/2$ - Input level

¹toggeling with restart

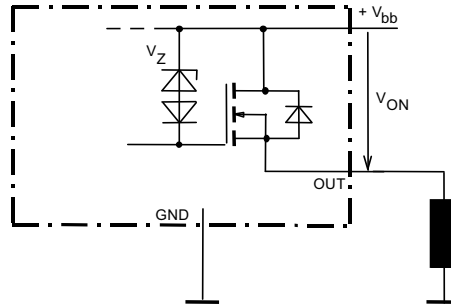
Terms

each channel



Inductive and overvoltage output clamp

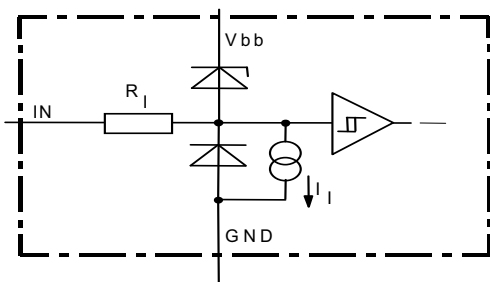
each channel



V_{ON} clamped to 47 V min.

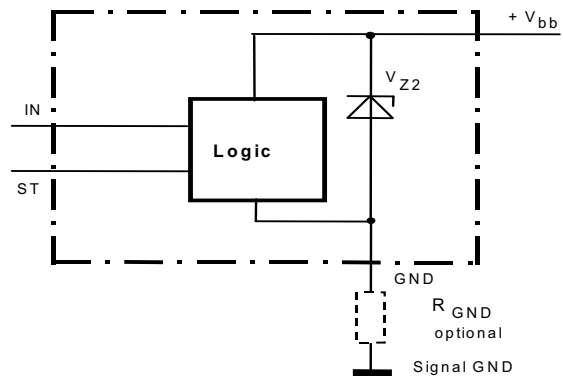
Input circuit (ESD protection)

each channel



The use of ESD zener diodes as voltage clamp at DC conditions is not recommended

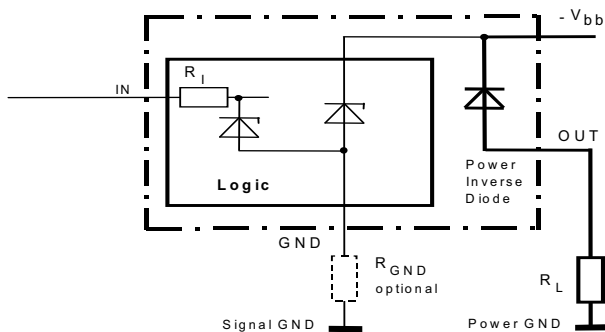
Overvoltage protection of logic part



$V_{Z2}=V_{bb(AZ)}=47$ V min.,
 $R_I=3$ k Ω typ., $R_{GND}=150\Omega$

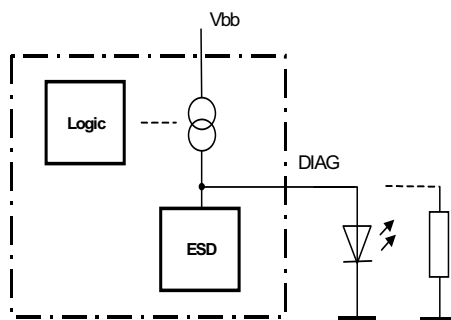
Reverse battery protection

each channel



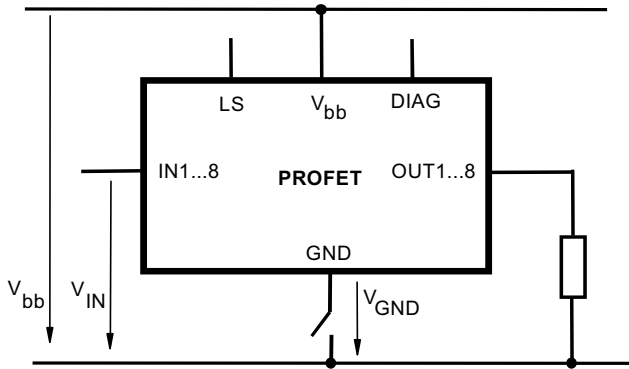
$R_{GND}=150\Omega$, $R_I=3k\Omega$ typ.,
 Temperature protection is not active during inverse current

Common diagnostic output

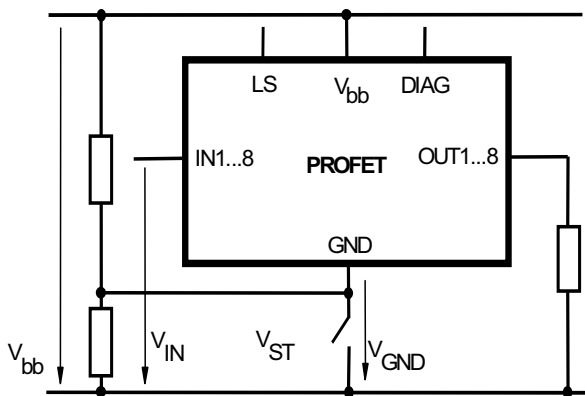


Output current typ. 2 mA

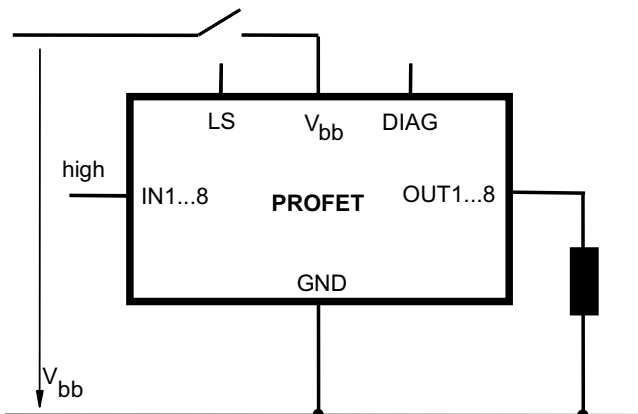
GND disconnect



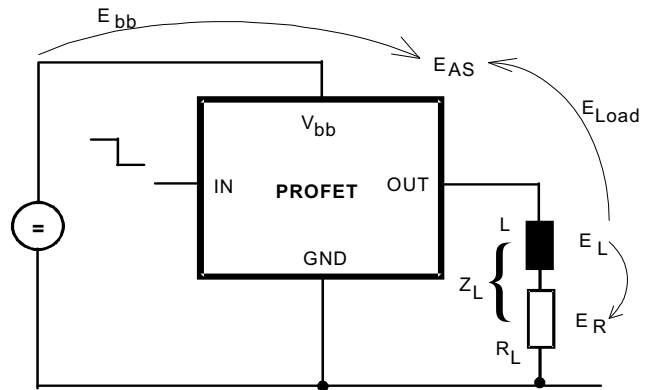
GND disconnect with GND pull up



V_{bb} disconnect with charged inductive load



Inductive Load switch-off energy dissipation, each channel



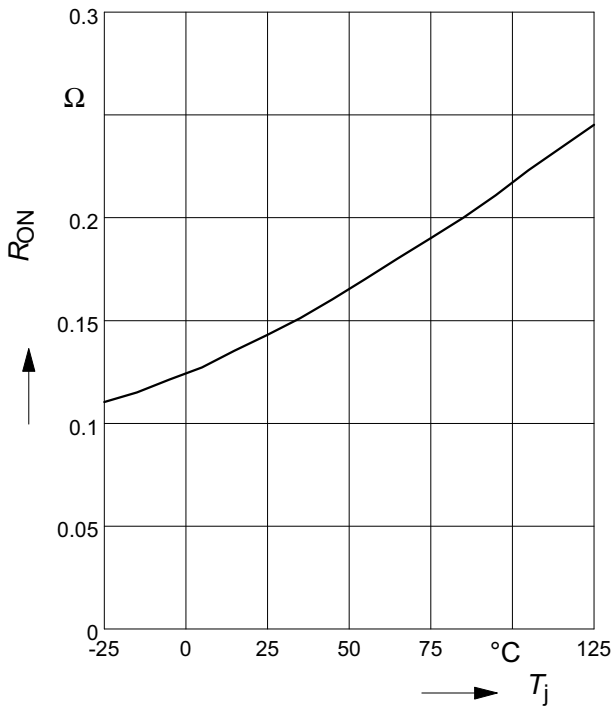
Energy stored in load inductance: $E_L = \frac{1}{2} * L * I_L^2$

While demagnetizing load inductance, the energy dissipated in PROFET is $E_{AS} = E_{bb} + E_L - E_R = V_{ON(CL)} * i_L(t) dt$, with an approximate solution for $R_L > 0$:

$$E_{AS} = V_{OUT(CL)} * \frac{L}{R_L} * \left[\frac{V_{BB} - V_{OUT(CL)}}{R_L} * \ln \left(1 - \frac{R_L * I_L}{V_{BB} - V_{OUT(CL)}} \right) + I_L \right]$$

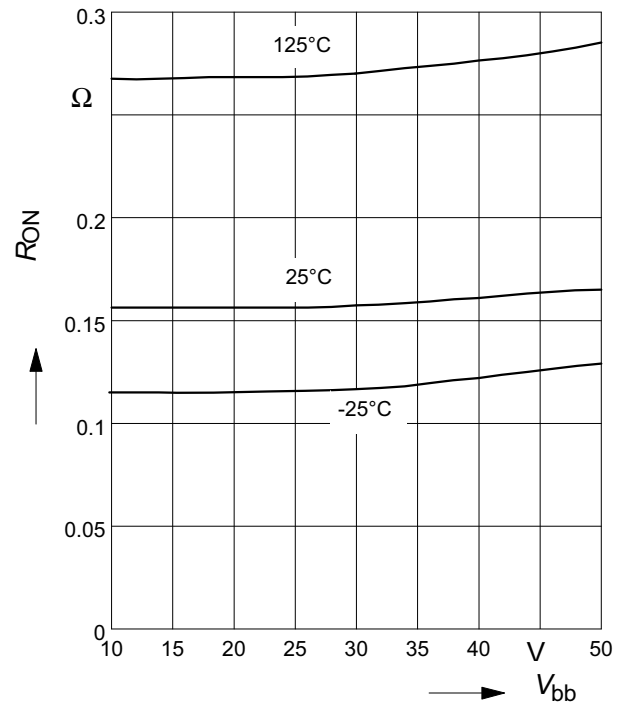
Typ. on-state resistance

$R_{ON} = f(T_j)$; $V_{bb} = 15V$; $V_{in} = \text{high}$



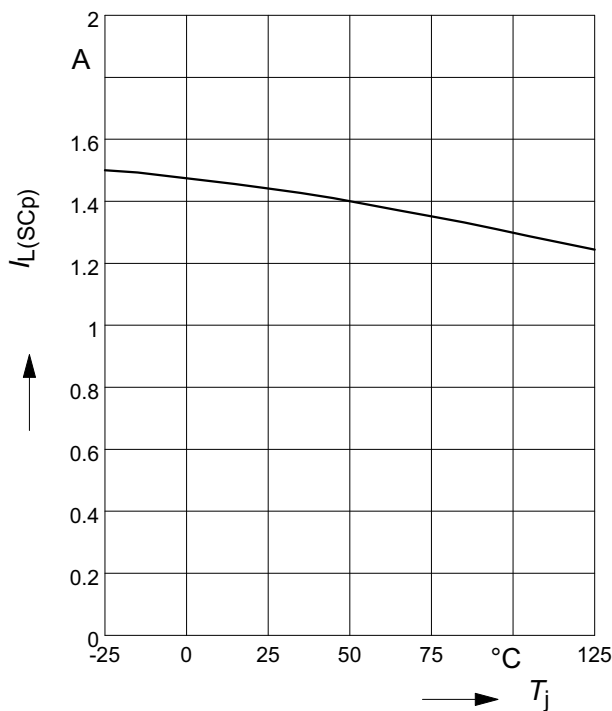
Typ. on-state resistance

$R_{ON} = f(V_{bb})$; $I_L = 0.5A$; $V_{in} = \text{high}$



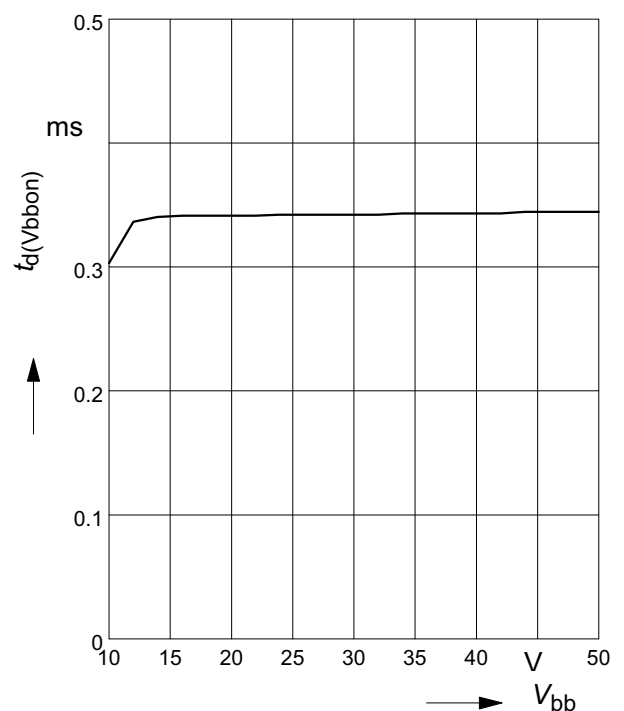
Typ. initial peak short circuit current limit

$I_{L(SCP)} = f(T_j)$; $V_{bb} = 24V$



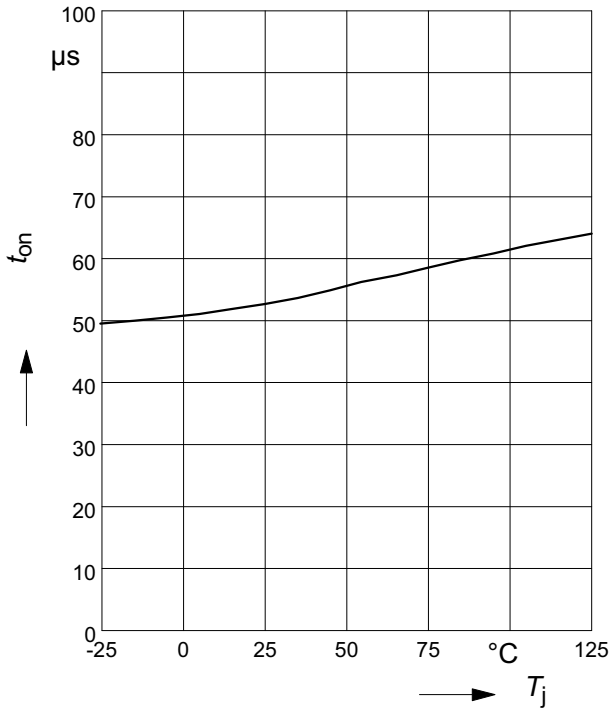
Typ. input delay time at switch on V_{bb}

$t_d(V_{bbon}) = f(V_{bb})$; $T_j = -25...125^{\circ}C$



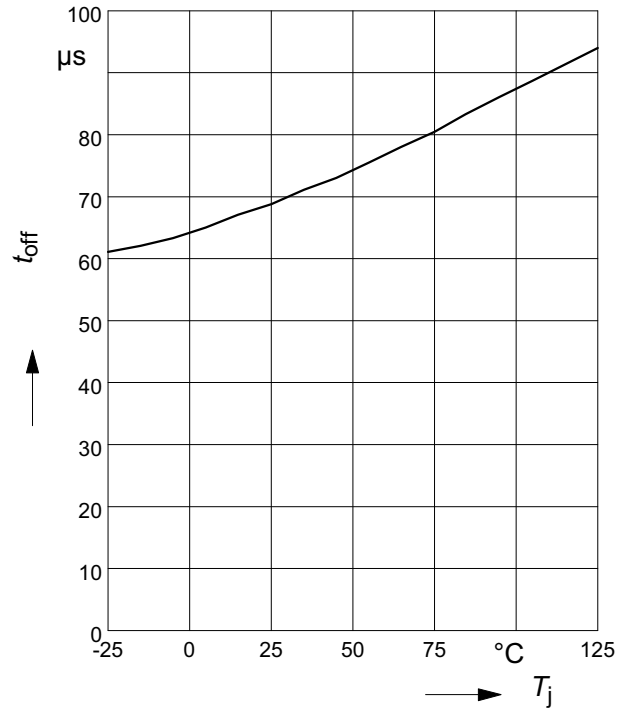
Typ. turn on time

$t_{on} = f(T_j); R_L = 47\Omega$



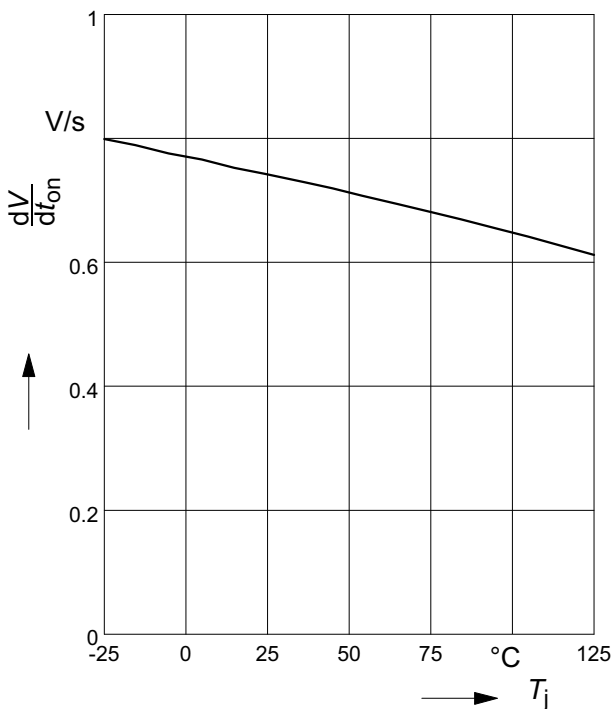
Typ. turn off time

$t_{off} = f(T_j); R_L = 47\Omega$



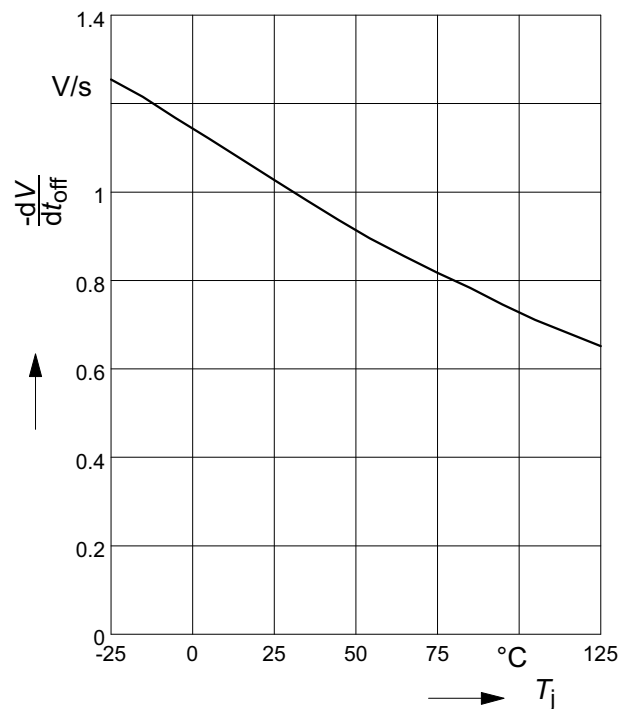
Typ. slew rate on

$dV/dt_{on} = f(T_j); R_L = 47\Omega, V_{bb} = 15V$



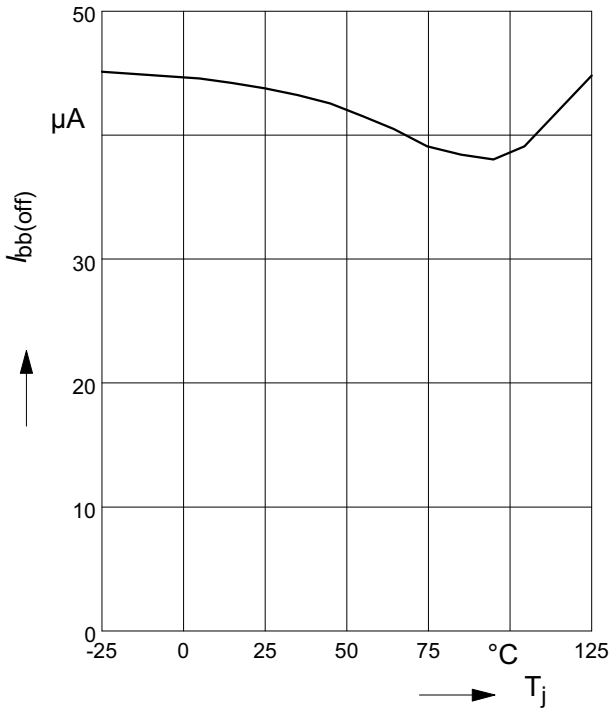
Typ. slew rate off

$-dV/dt_{off} = f(T_j); R_L = 47\Omega, V_{bb} = 15V$



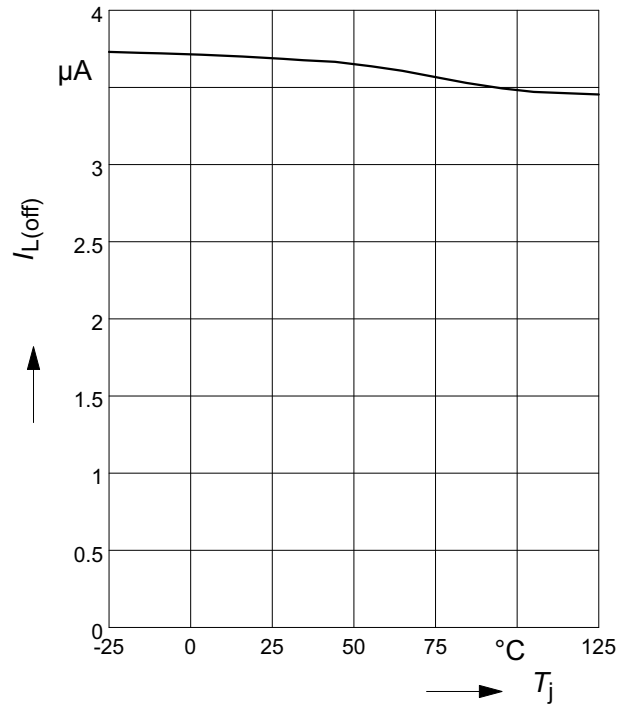
Typ. standby current

$I_{bb(off)} = f(T_j)$; $V_{bb} = 30V$; $V_{IN} = low$



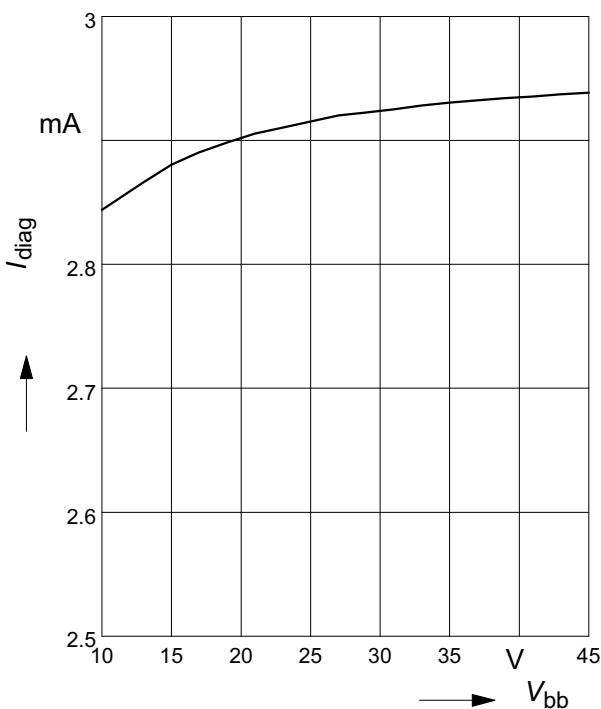
Typ. leakage current

$I_{L(off)} = f(T_j)$; $V_{bb} = 30V$; $V_{IN} = low$



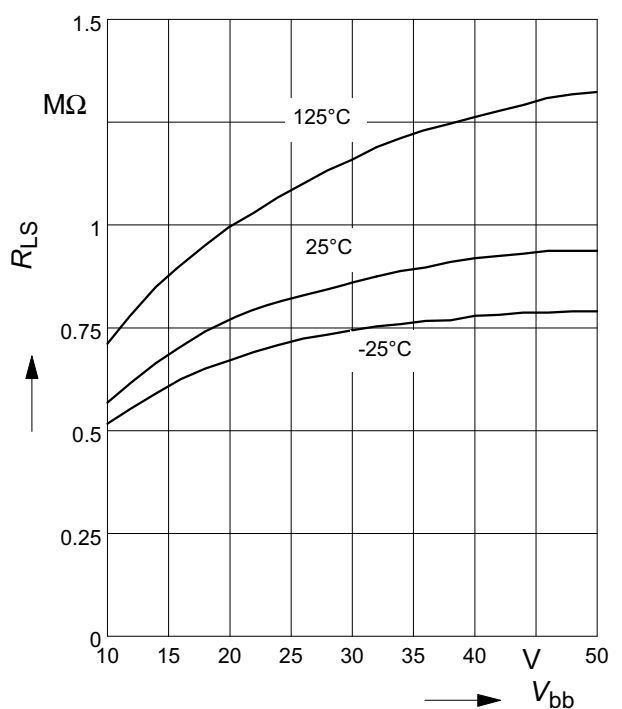
Typ. common diagnostic output current

$I_{diag} = f(V_{bb})$; $T_j = 135°C$



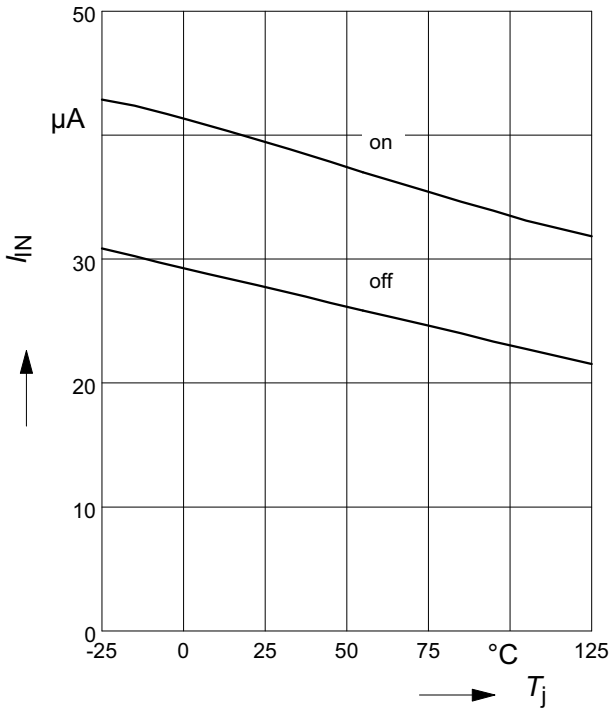
Typ. internal pull down resistor at LS-pin

$R_{LS} = f(V_{bb})$; $V_{LS} = V_{bb}$



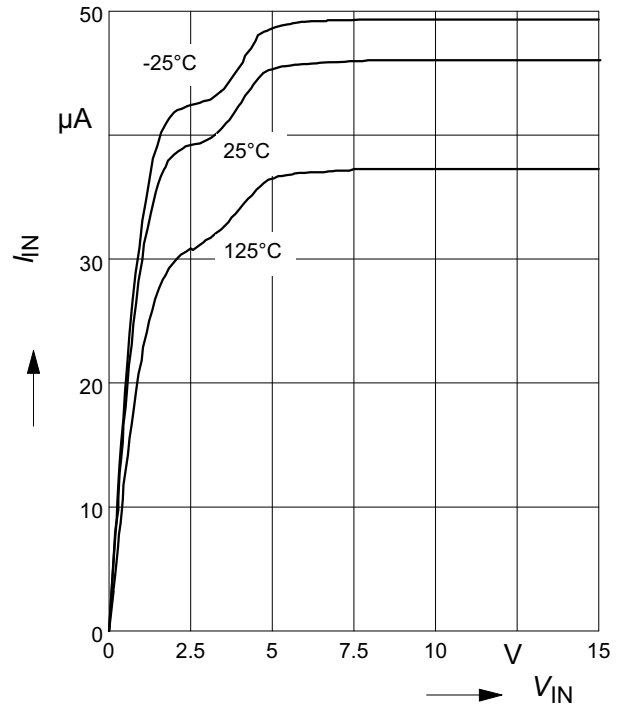
Typ. input current @ CMOS level

$I_{IN(on/off)} = f(T_j)$; $V_{bb} = 15V$; $V_{IN} = \text{low/high}$
 $V_{INlow} \leq 0,8V$; $V_{INhigh} = 2,2V$



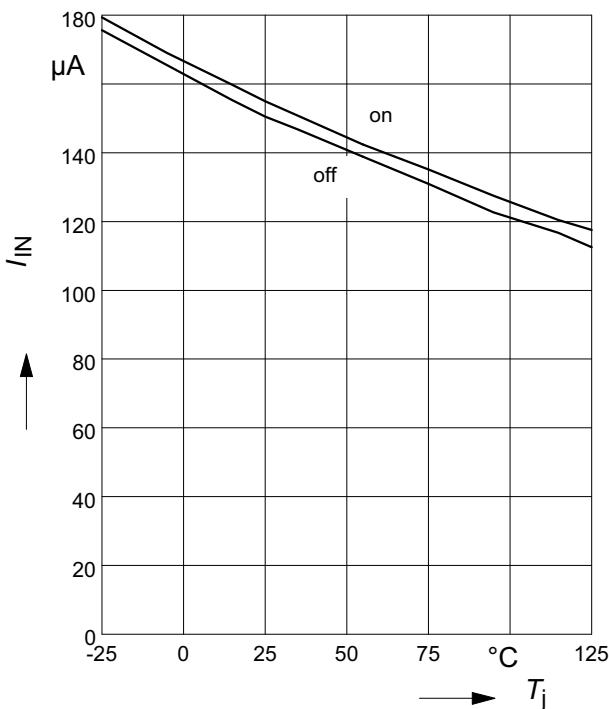
Typ. input current @ CMOS level

$I_{IN} = f(V_{IN})$; $V_{bb} = 15V$



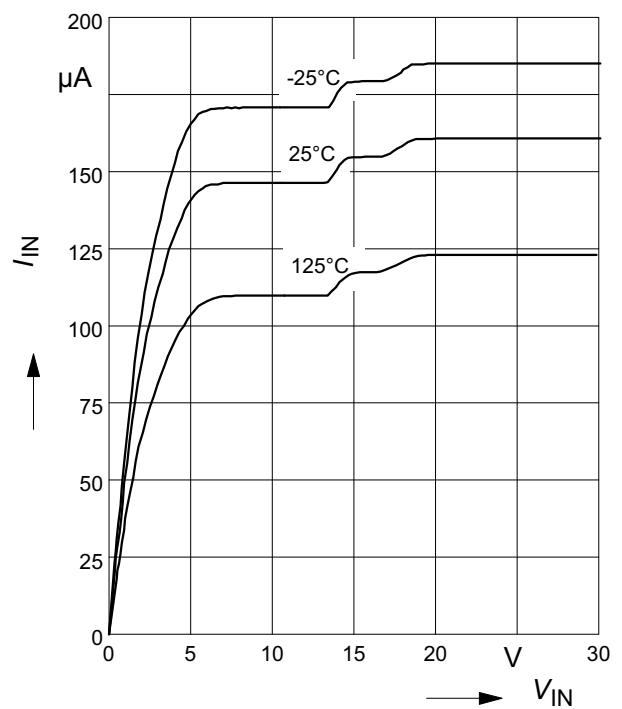
Typ. input current @ V_{bb}/2 level

$I_{IN(on/off)} = f(T_j)$; $V_{bb} = 30V$; $V_{IN} = \text{low/high}$



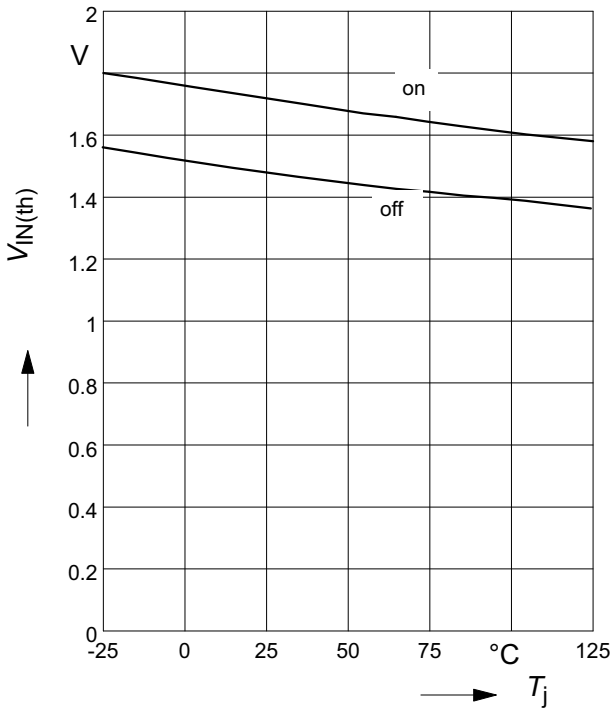
Typ. input current @ V_{bb}/2 level

$I_{IN} = f(V_{IN})$; $V_{bb} = 30V$



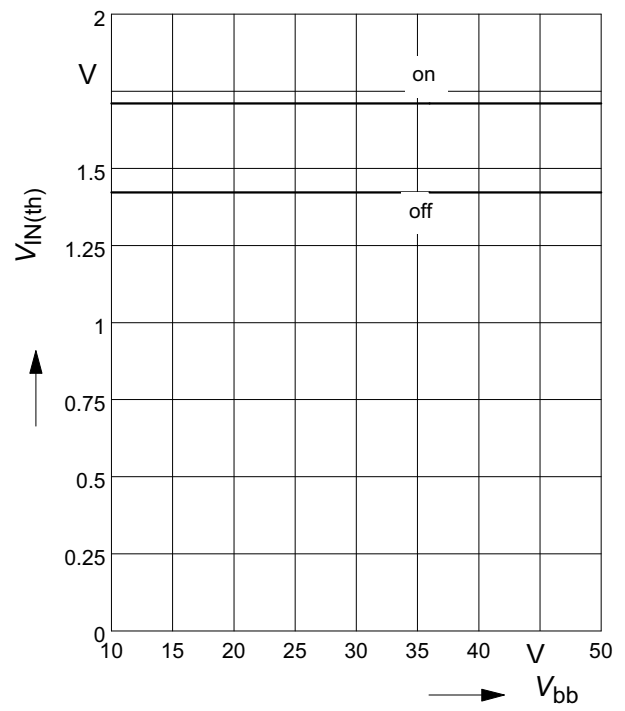
**Typ. input threshold voltage
@ CMOS level**

$V_{IN(th)} = f(T_j) ; V_{bb} = 15V$



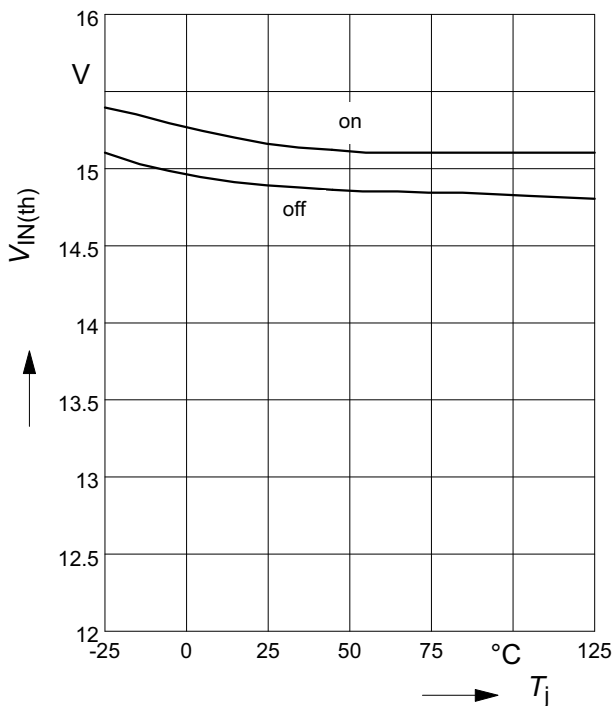
**Typ. input threshold voltage
@ CMOS level**

$V_{IN(th)} = f(V_{bb}) ; T_j = 25^{\circ}C$



**Typ. input threshold voltage
@ V_{bb}/2 level**

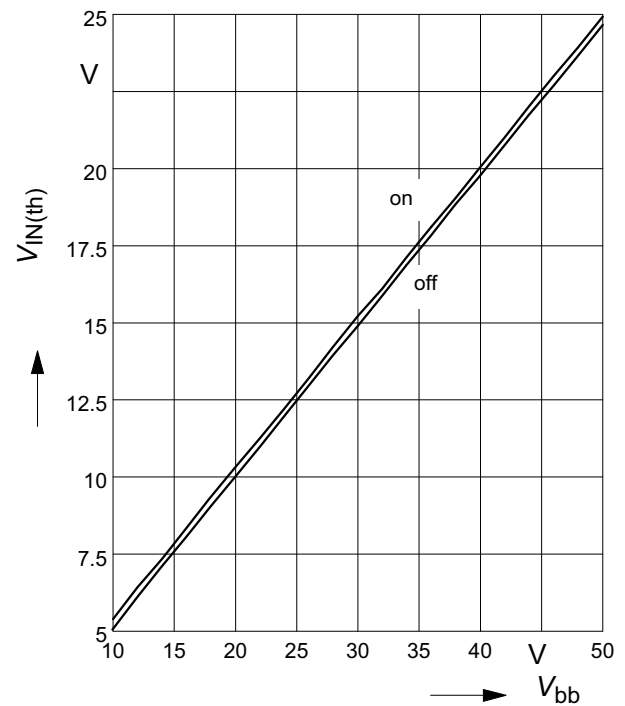
$V_{IN(th)} = f(T_j) ; V_{bb} = 30V$



Typ. input threshold voltage

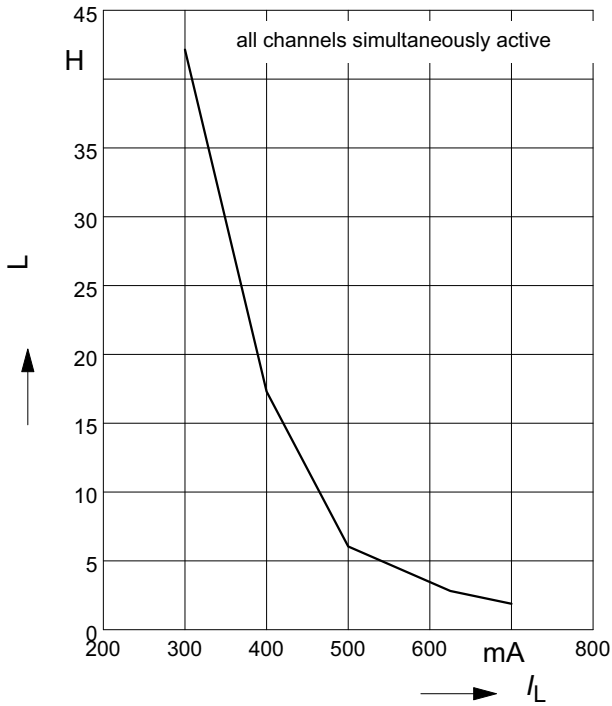
@ V_{bb}/2 level: LS-pin connected to V_{bb}

$V_{IN(th)} = f(V_{bb}) ; T_j = 25^{\circ}C$



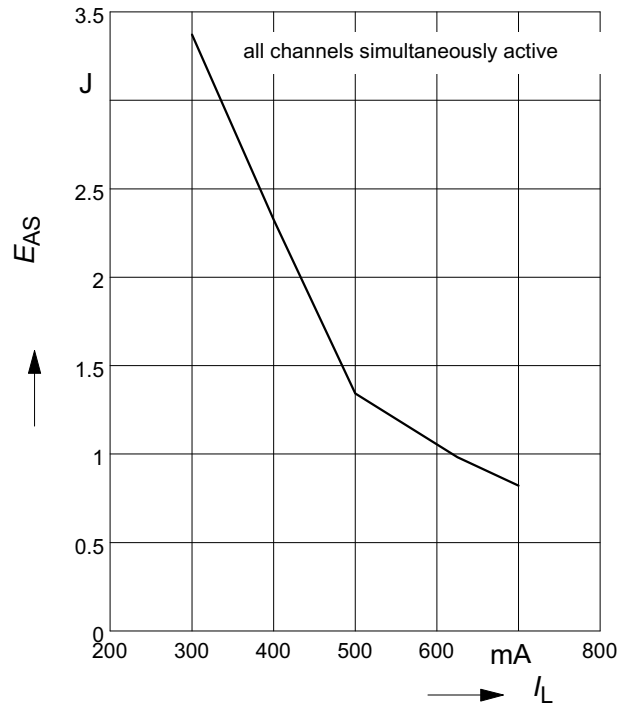
Maximum allowable load inductance for a single switch off, calculated

$L = f(I_L); T_{jstart}=125^{\circ}C, V_{bb}=24V, R_L=0\Omega$



Maximum allowable inductive switch-off energy, single pulse

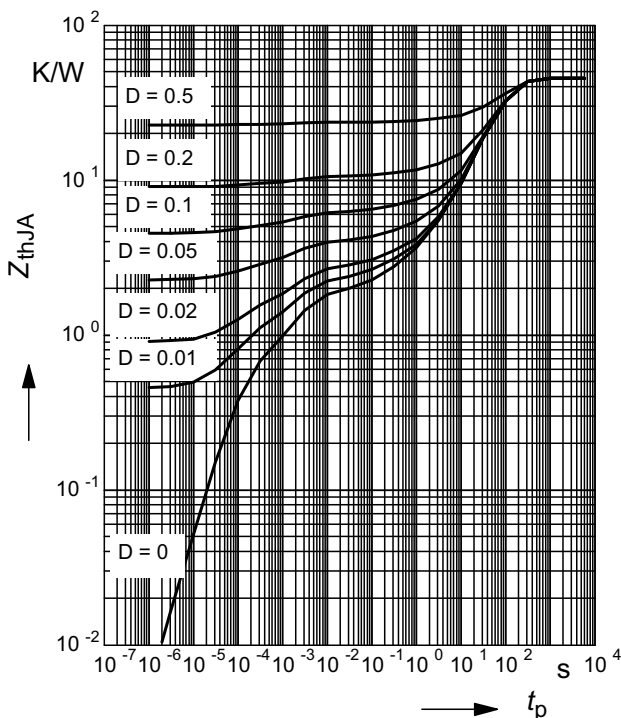
$E_{AS} = f(I_L); T_{jstart} = 125^{\circ}C, V_{bb} = 24V$



Typ. transient thermal impedance $Z_{thJA}=f(t_p)$ @ min. footprint

$Z_{thJA}=f(t_p)$ @ min. footprint

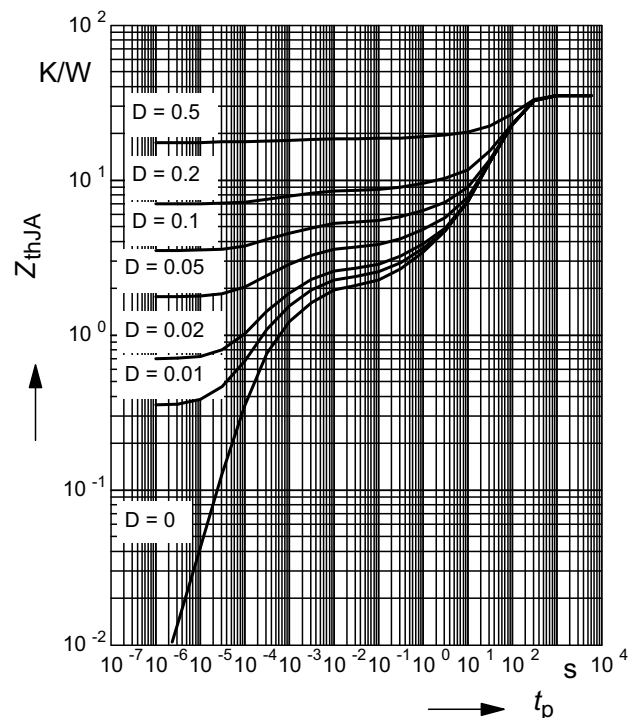
Parameter: $D=t_p/T$



Typ. transient thermal impedance $Z_{thJA}=f(t_p)$ @ 6cm² heatsink area

$Z_{thJA}=f(t_p)$ @ 6cm² heatsink area

Parameter: $D=t_p/T$



Timing diagrams

Figure 1a: V_{bb} turn on:

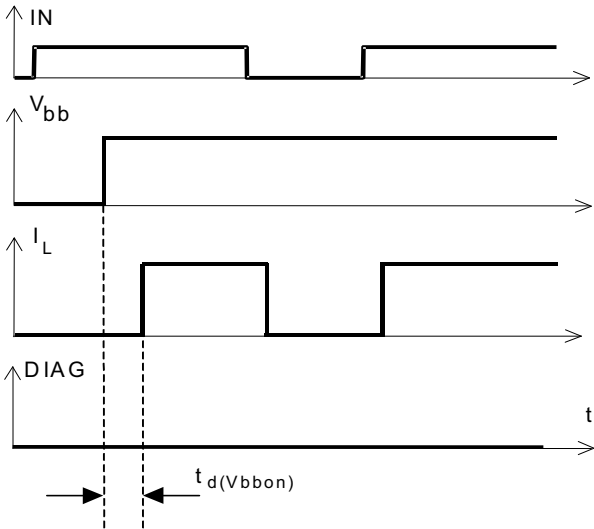


Figure 2b: Switching a lamp

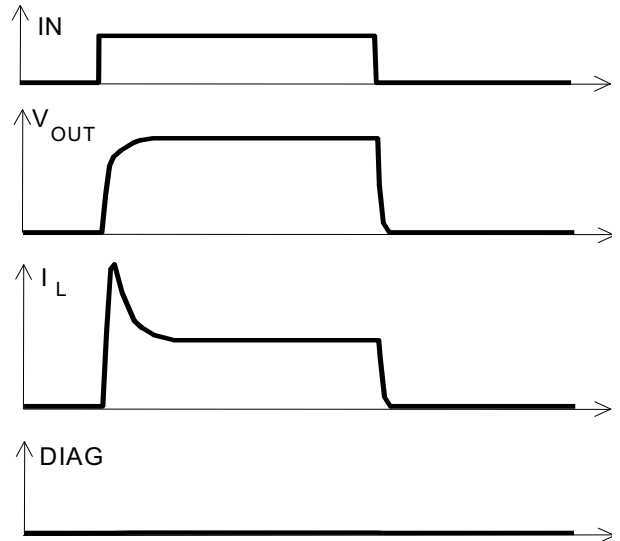


Figure 2a: Switching a resistive load, turn-on/off time and slew rate definition

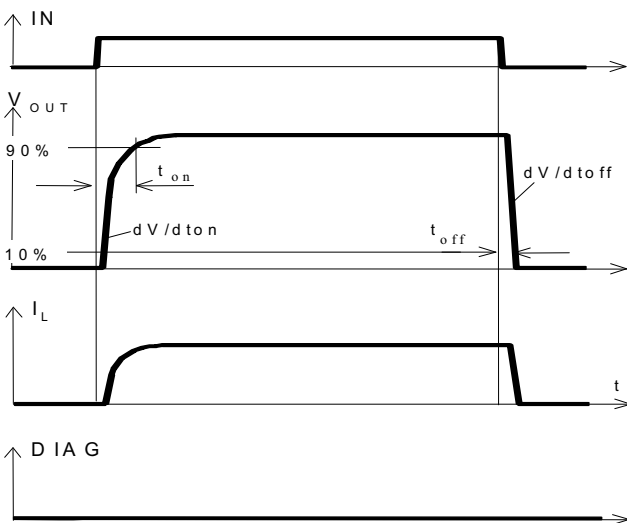
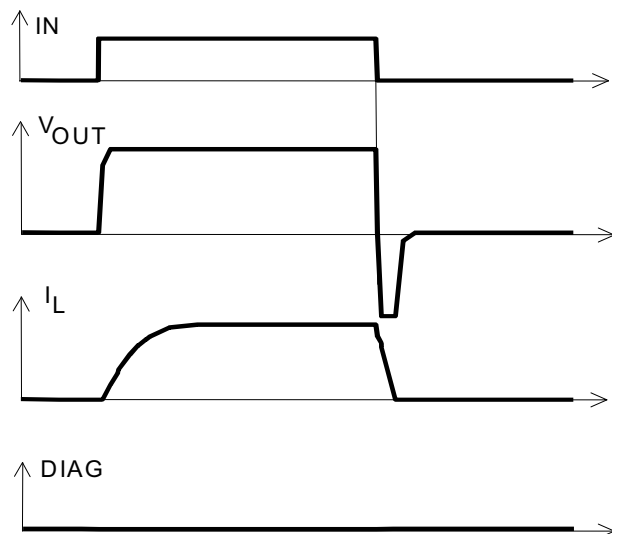


Figure 2c: Switching an inductive load



Timing diagrams

Figure 1a: Vbb turn on:

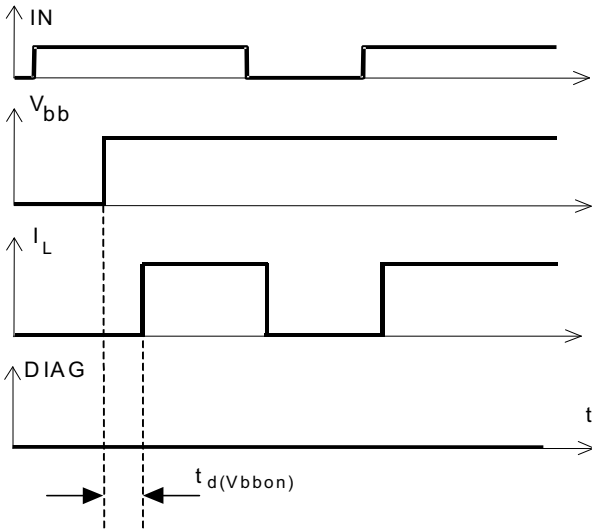


Figure 2b: Switching a lamp

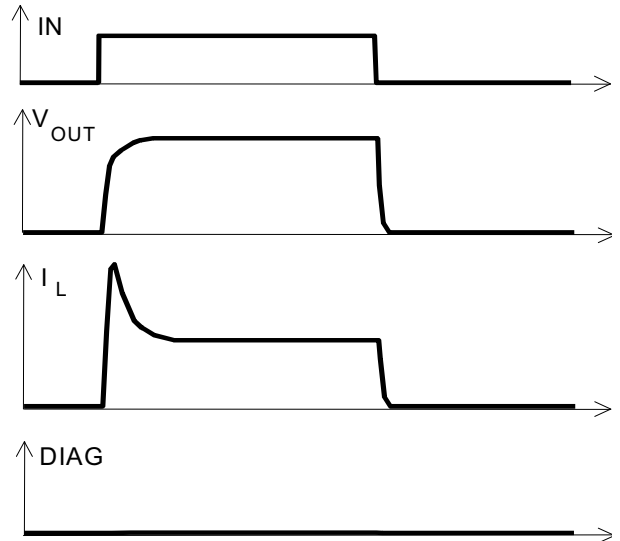


Figure 2a: Switching a resistive load, turn-on/off time and slew rate definition

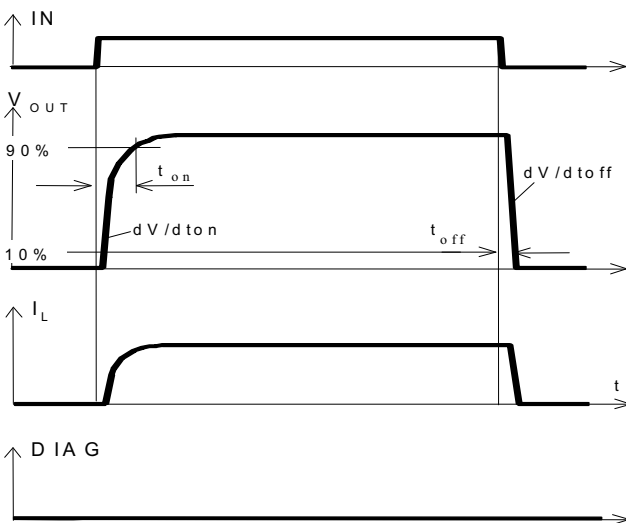


Figure 2c: Switching an inductive load

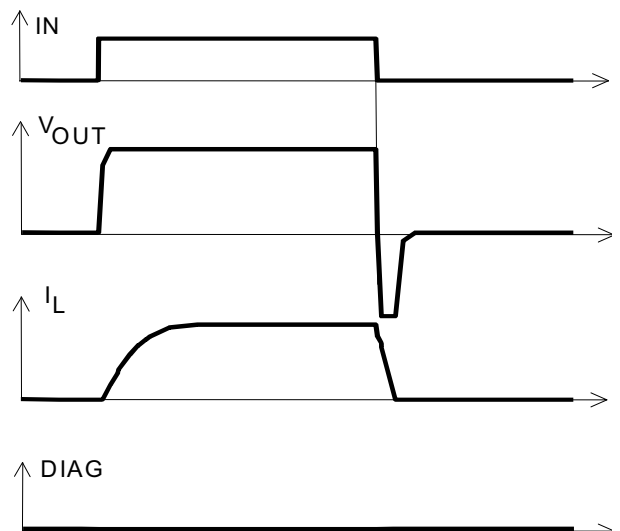
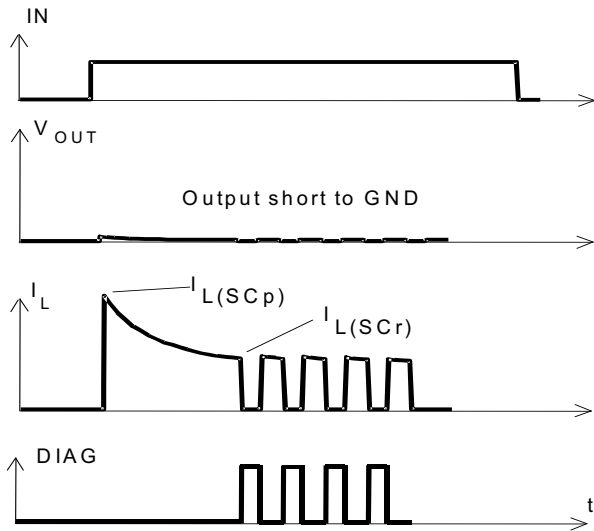


Figure 3a: Turn on into short circuit, shut down by overtemperature, restart by cooling



Heating up of the chip may require several milliseconds, depending on external conditions.

Figure 3b: Short circuit in on-state shut down by overtemperature, restart by cooling

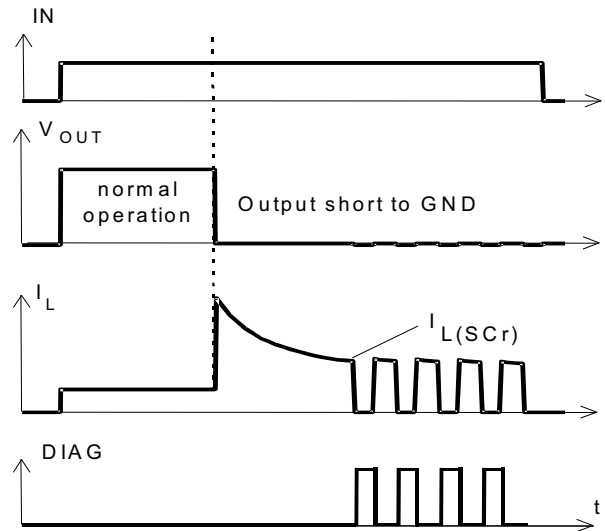


Figure 4: Overtemperature: Reset if $T_j < T_{jt}$

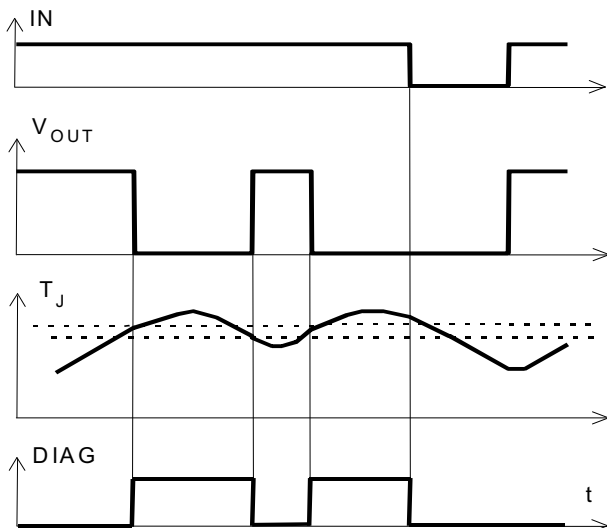
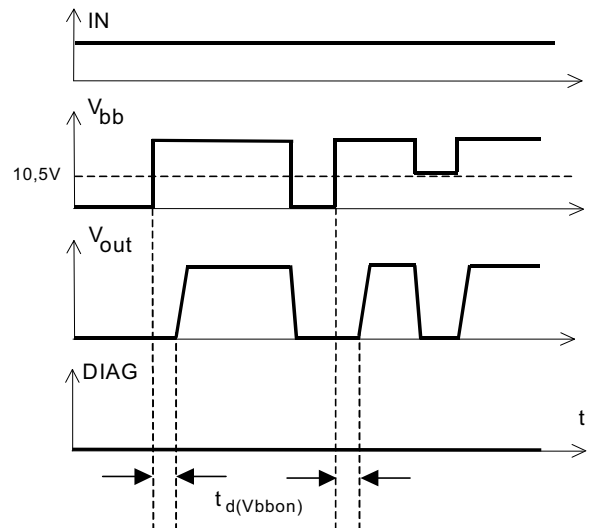


Figure 5: Undervoltage shutdown and restart



Package Outlines

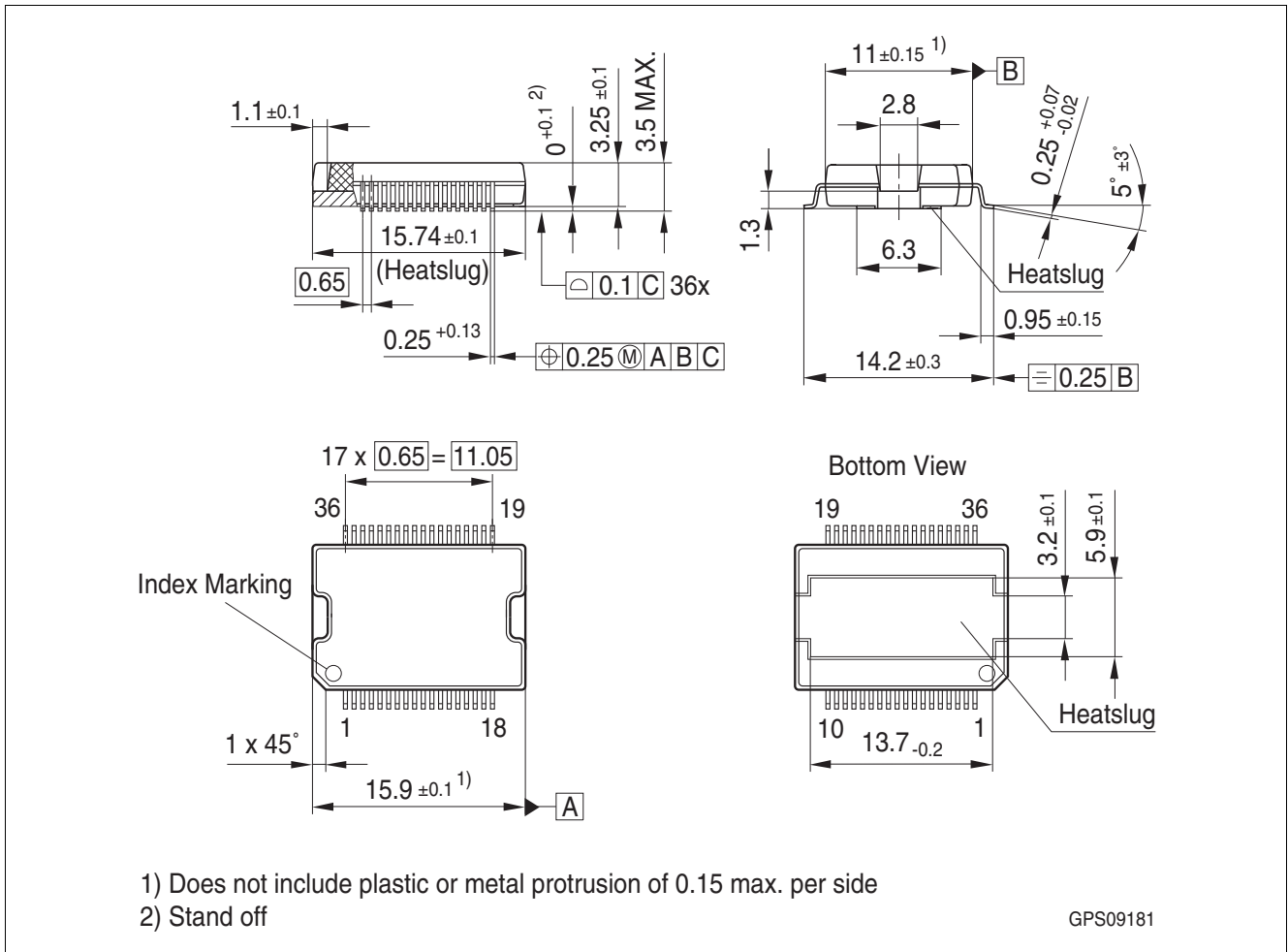


figure 6: PG-DSO-36

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

For further information on alternative packages, please visit our website:
<http://www.infineon.com/packages>.

Dimensions in mm

Revision History

Revision	Date	Changes
1.2	2014-12-15	Update of functional description LS-Pin on page 9. Changed wording of the sentence: "Therefore you have either to connect the LS-pin to device GND (state 1) or to supply voltage (state 2). Added cover page Changed energy formula Changed package drawing
1.1	2007-10-18	RoHS-compliant DSO package version of the BTS4880R All pages: Infineon logo updated Page 1: Added "AEC qualified" and "RoHS" logo, added "Green Product (RoHS compliant)" and "AEC qualified" statement to feature list, package names changed to RoHS compliant versions, updated package drawing. Page 21: Package names changed to RoHS compliant versions, added "Green Product" description added Revision History added Legal Disclaimer Package name changed to PG-DSO-36

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- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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